





SLLS500A - MAY 2001 - REVISED MARCH 2005

#### DIFFERENTIAL BUS TRANSCEIVER

#### **FEATURES**

- One-Fourth Unit Load Allows up to 128 **Devices on a Bus**
- **ESD Protection for Bus Terminals:** 
  - ±15-kV Human Body Model
  - ±8-kV IEC61000-4-2, Contact Discharge
  - ±15-kV IEC61000-4-2, Air-Gap Discharge
- Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482: 1987(E)
- Controlled Driver Output-Voltage Slew Rates **Allow Longer Cable Stub Lengths**
- Designed for Signaling Rates<sup>†</sup> Up to 250-kbps
- Low Disabled Supply Current . . . 250 µA Max
- **Thermal Shutdown Protection**
- Open-Circuit Fail-Safe Receiver Design
- Receiver Input Hysteresis . . . 70 mV Typ
- Glitch-Free Power-Up and Power-Down Protection

#### **APPLICATIONS**

- **Utility Meters**
- **Industrial Process Control**
- **Building Automation**

#### DESCRIPTION

The SN65LBC182 and SN75LBC182 are differential data line transceivers with a high level of ESD protection in the trade-standard footprint of the SN75176. They are designed for balanced transmission lines and meet ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC182 and SN75LBC182 combine a 3-state, differential line driver and differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a direction control.

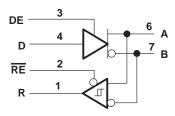
The driver outputs and the receiver inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus. This port operates over a wide range of common-mode voltage, making the device suitable for party-line applications. The device also includes additional features for party-line data buses in electrically noisy environment applications such as industrial process control or power inverters.

The SN75LBC182 and SN65LBC182 bus pins also exhibit a high input resistance equivalent to one-fourth unit load allowing connection of up to 128 similar devices on the bus. The high ESD tolerance protects the device for cabled connections. (For an even higher level of protection, see the SN65/75LBC184, literature number SLLS236.)

The differential driver design incorporates slew-rate-controlled outputs sufficient to transmit data up to 250 kbps. Slew-rate control allows longer unterminated cable runs and longer stub lengths from the main backbone than possible with uncontrolled voltage transitions. The receiver design provides a fail-safe output of a high level when the inputs are left floating (open circuit). Very low device supply current can be achieved by disabling the driver and the receiver.

The SN65LBC182 is characterized for operation from -40°C to 85°C, and the SN75LBC182 is characterized for operation from 0°C to 70°C.

#### functional block diagram



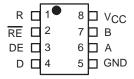


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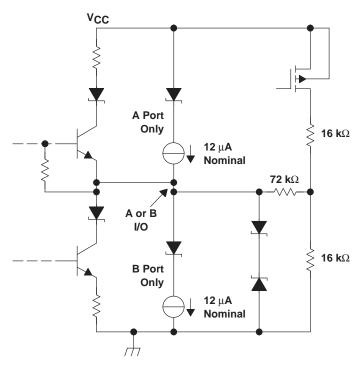
†The signaling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



SN65LBC182D (Marked as 6LB182) SN75LBC182D (Marked as 7LB182) SN65LBC182P (Marked as 65LBC182) SN75LBC182P (Marked as 75LBC182) (TOP VIEW)



### schematic of inputs and outputs



#### **Function Tables**

#### **DRIVER**

INPUT	ENABLE	OUTPUTS			
D	DE	Α	В		
Н	Н	Н	L		
L	Н	L	Н		
Х	L	Z	Z		
Open	Н	Н	L		

#### **RECEIVER**

DIFFERENTIAL INPUTS	ENABLE RE	OUTPUT R
V <sub>ID</sub> ≥ 0.2 V	L	Н
$-0.2V < V_{ID} < 0.2 V$	L	?
V <sub>ID</sub> ≤ -0.2 V	L	L
X	Н	Z
Open	L	Н

#### **AVAILABLE OPTIONS**

		PACKAGE
TA	PLASTIC SMALL-OUTLINE <sup>†</sup> (JEDEC MS-012)	PLASTIC DUAL-IN-LINE PACKAGE (JEDEC MS-001)
0°C to 70°C	SN75LBC182D	SN75LBC182P
-40°C to 85°C	SN65LBC182D	SN65LBC182P

<sup>†</sup> Add R suffix for taped and reel.

<sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



#### absolute maximum ratings† over operating free-air temperature range unless otherwise noted

Supply voltage range, (see Note 1) V <sub>CC</sub>	
Voltage range at any bus terminal (A or B)	–15 V to 15 V
Input voltage, V <sub>I</sub> (D, DE, R or RE)	–0.3 V to 7 V
Receiver output current, IO	±20 mA
Electrostatic discharge: Human body model (see Note 2)	A, B, GND
	All pins 3 kV
Contact discharge (IEC61000-4-2)	A, B, GND 8 kV
Air discharge (IEC61000-4-2)	A, B, GND
Continuous total power dissipation	See Dissipation Rating Table

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### **DISSIPATION RATING TABLE**

PACKAGE	$\begin{aligned} & \textbf{T}_{\pmb{A}} \leq \textbf{25}^{\circ}\textbf{C} \\ & \textbf{POWER RATING} \end{aligned}$	DERATING FACTOR‡ ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	
D	725 mW	5.8 mW/°C	464 mW	377 mW	
Р	1150 mW	9.2 mW/°C	736 mW	598 mW	

<sup>&</sup>lt;sup>‡</sup> This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow. NOTE: The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature

#### recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>				5	5.25	V
Voltage at any bus I/O terminal (separately of	r common mode) V <sub>I</sub> or V <sub>IC</sub>		-7		12	V
High-level input voltage, VIH	D, DE, RE		2			
Low-level input voltage, V <sub>IL</sub>	D, DE, RE	D, DE, RE			0.8	V
Differential input voltage, V <sub>ID</sub> (see Note 3)			-12		12	V
	Driver		-60		60	
Output current, IO	Receiver		-8		4	mA
Operating free air temperature T.	SN65LBC182		-40		85	°C
Operating free-air temperature, T <sub>A</sub>	SN75LBC182		0		70	-0

NOTE 3: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.



NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

<sup>2.</sup> Tested in accordance with JEDEC Standard 22, Test Method A114-A.

## driver electrical characteristics over recommended operating conditions

	PARAMETER	TEST COND	MIN	TYP†	MAX	UNIT		
VIK	Input clamp voltage		I <sub>I</sub> = -18 mA		-1.5			V
VO	Output voltage		IO = 0		0		VCC	V
15.7	Differential autout autour		$R_L = 54 \Omega$ ,	See Figure 1	1.5	2.2	VCC	V
IVODI	Differential output voltage	$V_{test} = -7 V \text{ to } 12 V,$	See Figure 2	1.5	2.2	VCC	V	
$\Delta V_{OD}$	Change in magnitude of differentia	al output voltage	0		-0.2		0.2	
Voc(ss)	Steady-state common-mode output	ut voltage	See Figure 1		1		3	V
ΔVOC(SS)	Change in steady-state common-movel voltage	0 5 4 14		-0.2		0.2	V	
VOC(PP)	Peak-to-peak change in common- voltage during state transitions	See Figures 1 and 4			0.8		٧	
loz	High-impedance output current		See receiver input cur	rents				
lіН	High-level input current (D, DE)		V <sub>I</sub> = 2.4 V				50	μΑ
I <sub>L</sub>	Low-level input current (D, DE)	V <sub>I</sub> = 0.4 V		-50			μΑ	
los	Short-circuit output current	$V_0 = -7 \text{ V to } 12 \text{ V}$		-250		250	mA	
	O-marks assumed	SN75LBC182	No load, DE at V <sub>CC</sub> ,	DEV		12	25	4
Icc	Supply current	SN65LBC182		RE at V <sub>CC</sub>		12	30	mA

 $<sup>^{\</sup>dagger}$  All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

# driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST C	MIN	TYP	MAX	UNIT	
t <sub>r</sub>	Differential output signal rise time			0.25	0.72	1.2	
t <sub>f</sub>	Differential output signal fall time			0.25	0.73	1.2	
t <sub>PLH</sub>	Propagation delay time, low-to-high-level output	$R_L = 54 \Omega$ , See Figure 3	$C_L = 50 pF$ ,			1.3	μs
tPHL	Propagation delay time, high-to-low-level output	occ rigure 3				1.3	
t <sub>sk(p)</sub>	Pulse skew (tpHL - tpLH)				0.075	0.15	
<sup>t</sup> PZH	Output enable time to high level	D 440.0	0 5 5			3.5	_
t <sub>PHZ</sub>	Output disable time from high level	$R_L = 110 \Omega$	$R_L = 110 \Omega$ , See Figure 5			3.5	μs
tPZL	Output enable time to low level	D 440.0	0			3.5	_
tPLZ	Output disable time from low level	$R_L = 110 \Omega$ ,	See Figure 6			3.5	μs



# receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONI	DITIONS	MIN	TYP	MAX	UNIT
V <sub>IT+</sub>	Positive-going input threshold voltage					0.2	
$V_{IT-}$	Negative-going input threshold voltage			-0.2			V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT-</sub> )				70		mV
٧ıĸ	Enable-input clamp voltage	I <sub>I</sub> = -18 mA		-1.5			V
Vон	High-level output voltage	$V_{ID} = 200 \text{ mV}, I_{O} = -8 \text{ mA},$	See Figure 7	2.8			V
VOL	Low-level output voltage	$V_{ID} = 200 \text{ mV}, I_O = 4 \text{ mA},$	See Figure 7			0.4	V
loz	High-impedance-state output current	$V_0 = 0.4 \text{ to } 2.4 \text{ V}$				±1	μΑ
		$V_{IH} = 12 \text{ V}, \ V_{CC} = 5 \text{ V}$				250	
l	Post insulations of	V <sub>IH</sub> = 12 V, V <sub>CC</sub> = 0 V	Other lead of O.V			250	
l <sub>l</sub>	Bus input current	$V_{IH} = -7 \text{ V}, V_{CC} = 5 \text{ V}$	Other input at 0 V	-200			μΑ
		$V_{IH} = -7 \text{ V}, V_{CC} = 0 \text{ V}$	]	-200			
lн	High-level input current (RE)	V <sub>IH</sub> = 2 V				50	μΑ
I <sub>IL</sub>	Low-level input current (RE)	V <sub>IL</sub> = 0.8 V		-50			μΑ
	Outside suggest	No local	DE at 0 V, RE at 0 V			3.5	mA
Icc	Supply current	No load	DE at 0 V, RE at V <sub>CC</sub>		175	250	μΑ

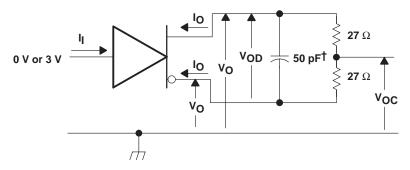
<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

# receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>r</sub>	Differential output signal rise time			20		
tf	Differential output signal fall time	05		20		
tPLH Propagation delay time, low-to-high-level output		C <sub>L</sub> = 50 pF, See Figure 7			150	ns
tPHL	Propagation delay time, high-to-low-level output				150	
<sup>t</sup> PZH	Output enable time to high level				100	
tPZL	Output enable time to low level	See Figure 8			100	ns
tPHZ	Output disable time from high level	See Figure o			100	20
tPLZ	Output disable time from low level				100	ns
tsk(p)	Pulse skew   tpHL - tpLH				50	ns



#### PARAMETER MEASUREMENT INFORMATION



†Includes probe and jig capacitance

Figure 1. Driver Test Circuit, V<sub>OD</sub> and V<sub>OC</sub> Without Common-Mode Loading

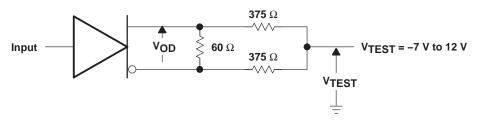
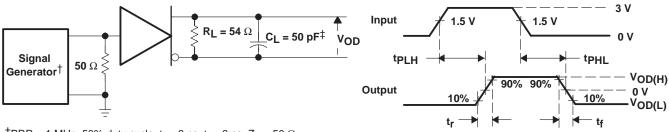


Figure 2. Driver Test Circuit, V<sub>OD</sub> With Common-Mode Loading



†PRR = 1 MHz, 50% duty cycle,  $t_{\Gamma}$  < 6 ns,  $t_{f}$  < 6 ns,  $Z_{O}$  = 50  $\Omega$  ‡Includes probe and jig capacitance

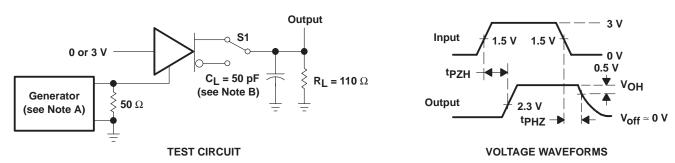
Figure 3. Driver Switching Test Circuit and Waveforms



Figure 4. V<sub>OC</sub> Definitions



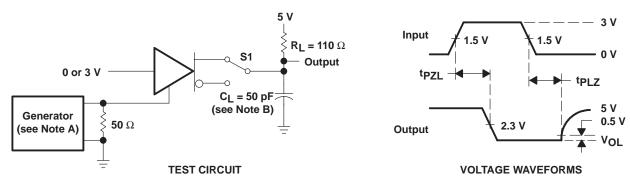
#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle,  $t_{\Gamma} \le 10$  ns,  $t_{f} \le 10$  ns,  $t_{O} = 50 \Omega$ .

B. C<sub>L</sub> includes probe and jig capacitance.

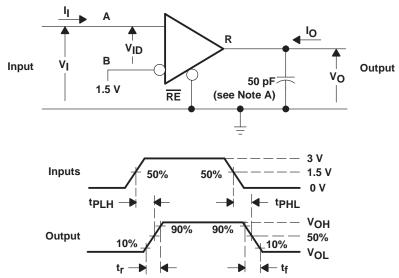
Figure 5. Driver tpzH and tpHZ Test Circuit and Voltage Waveforms



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1.25 kHz, 50% duty cycle,  $t_{\Gamma} \le 10$  ns,  $t_{\Gamma} \le 10$  ns,

B.  $C_L$  includes probe and jig capacitance.

Figure 6. Driver tpzL and tpLZ Test Circuit and Voltage Waveforms

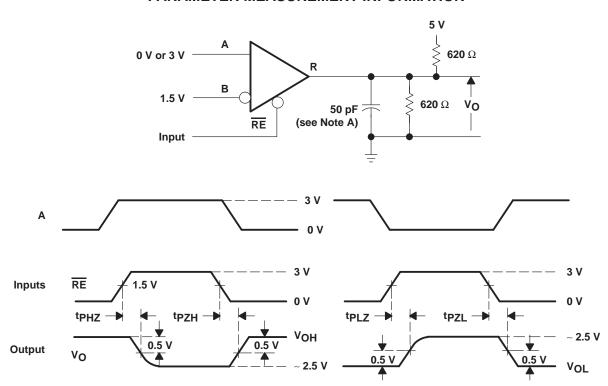


NOTE A: This value includes probe and jig capacitance (± 10%).

Figure 7. Receiver tplH and tpHL Test Circuit and Voltage Waveforms



#### PARAMETER MEASUREMENT INFORMATION



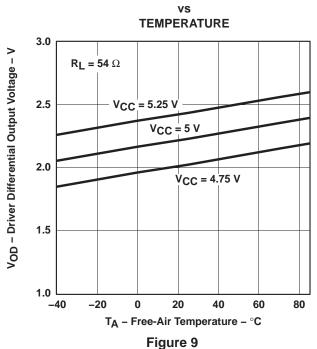
NOTE A: This value includes probe and jig capacitance ( $\pm$  10%).

Figure 8. Receiver tpzL, tpLZ, tpZH, and tpHZ Test Circuit and Voltage Waveforms

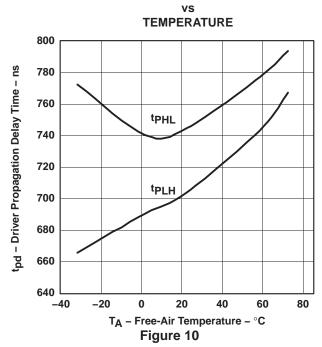


#### **TYPICAL CHARACTERISTICS**

#### **DRIVER DIFFERENTIAL OUTPUT VOLTAGE**



#### **DRIVER PROPAGATION DELAY TIME**



#### **DRIVER TRANSITION TIME**

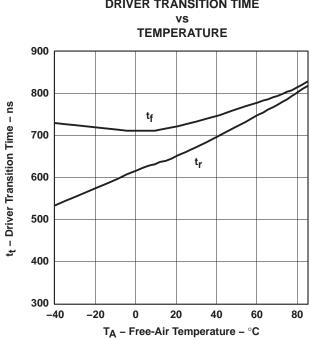
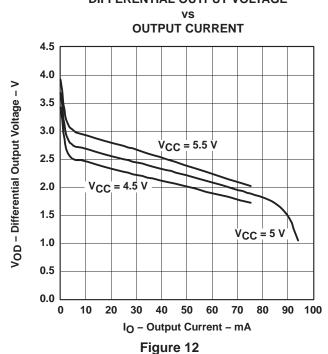


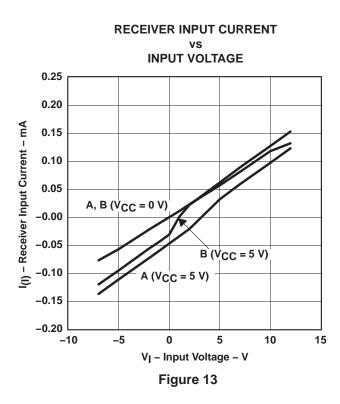
Figure 11

#### **DIFFERENTIAL OUTPUT VOLTAGE**





#### TYPICAL CHARACTERISTICS



# APPLICATION INFORMATION SN65LBC182 SN75LBC182 SN75LBC182 Up to 128 Transceivers

NOTE A: The line should be terminated at both ends in its characteristic impedance (R<sub>T</sub> = Z<sub>O</sub>). Stub lengths off the main line should be kept as short as possible.

Figure 14. Typical Application Circuit





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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN65LBC182D	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182	
SN65LBC182DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182	Samples
SN65LBC182DRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	6LB182	Samples
SN65LBC182P	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	65LBC182	Samples
SN75LBC182D	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	7LB182	
SN75LBC182DG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	7LB182	
SN75LBC182DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	7LB182	Samples
SN75LBC182P	LIFEBUY	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	75LBC182	

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



## **PACKAGE OPTION ADDENDUM**

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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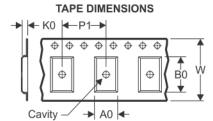
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# **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75LBC182DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN65LBC182DR	SOIC	D	8	2500	340.5	336.1	25.0	
SN75LBC182DR	SOIC	D	8	2500	340.5	336.1	25.0	

# PACKAGE MATERIALS INFORMATION

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LBC182D	D	SOIC	8	75	505.46	6.76	3810	4
SN65LBC182D	D	SOIC	8	75	507	8	3940	4.32
SN65LBC182P	Р	PDIP	8	50	506	13.97	11230	4.32
SN75LBC182D	D	SOIC	8	75	507	8	3940	4.32
SN75LBC182DG4	D	SOIC	8	75	507	8	3940	4.32
SN75LBC182P	Р	PDIP	8	50	506	13.97	11230	4.32

## **PACKAGE OUTLINE**

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# P (R-PDIP-T8)

# PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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